1. General description

NPN/PNP general-purpose double transistors in a very small SOT457 (SC-74) Surface-Mounted Device (SMD) plastic package.

2. Features and benefits

- Simplified circuit design
- Reduced component count
- · Reduced pick and place costs
- Qualified according to AEC-Q101 and recommended for use in automotive applications

3. Applications

· General-purpose switching and amplification

4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Per transistor; for the PNP transistor with negative polarity							
V _{CEO}	collector-emitter voltage	open base		-	-	50	V
I _C	collector current			-	-	150	mA

5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	C2	collector TR2		B2 B1 E1
2	E2	emitter TR2	<u> </u>	
3	C1	collector TR1		
4	E1	emitter TR1		TR2
5	B1	base TR1	TSOP6 (SOT457)	C2 E2 C1
6	B2	base TR2		sym082



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6. Ordering information

Table 3. Ordering information

Type number	Package	ckage				
	Name	Description	Version			
PIMZ2-Q	TSOP6	plastic, surface-mounted package (SC-74; TSOP6); 6 leads	<u>SOT457</u>			

7. Marking

Table 4. Marking codes

Type number	Marking code
PIMZ2-Q	M6

8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
Per transist	or; for the PNP transistor wit	h negative polarity	'	'	'	'
V _{CBO}	collector-base voltage	open emitter		-	60	V
V _{CEO}	collector-emitter voltage	open base		-	50	V
V _{EBO}	emitter-base voltage	open collector		-	7	V
I _C	collector current			-	150	mA
I _{CM}	peak collector current			-	200	mA
I _{BM}	peak base current			-	100	mA
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C	[1]	-	200	mW
Per device			•			
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C	[1]	-	300	mW
T _j	junction temperature			-	150	°C
T _{amb}	ambient temperature			-65	150	°C
T _{stg}	storage temperature			-65	150	°C

^[1] Device mounted on an FR4 Printed-Circuit Board (PCB).

9. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Per transistor							
$R_{th(j-a)}$	thermal resistance from junction to ambient	T _{amb} ≤ 25 °C	[1]	-	-	625	K/W
Per device							
$R_{th(j-a)}$	thermal resistance from junction to ambient	T _{amb} ≤ 25 °C	[1]	-	-	417	K/W

[1] Device mounted on an FR4 printed-circuit board.

PIMZ2-Q All information provided in this document is subject to legal disclaimers.

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10. Characteristics

Table 7. Characteristics

Symbol	Parameter	Conditions	Miı	тур Тур	Max	Unit
Per transist	or; for the PNP transistor	with negative polarity; unless otherwise	specified			
I _{CBO}	collector-base cut-off	V _{CB} = 60 V; I _E = 0 A; T _{amb} = 25 °C	-	-	100	nA
	current	V_{CB} = 60 V; I_{E} = 0 A; T_{j} = 150 °C; T_{amb} = 25 °C	-	-	50	μA
I _{EBO}	emitter-base cut-off current	V _{EB} = 7 V; I _C = 0 A; T _{amb} = 25 °C	-	-	100	nA
h _{FE}	DC current gain	V _{CE} = 6 V; I _C = 1 mA; T _{amb} = 25 °C	120	250	560	
TR1 (PNP)					·	
V _{CEsat}	collector-emitter saturation voltage	I_{C} = -50 mA; I_{B} = -5 mA; T_{amb} = 25 °C	-	-	-500	mV
C _c	collector capacitance	V _{CB} = -12 V; I _E = 0 A; i _e = 0 A; f = 1 MHz; T _{amb} = 25 °C	-	2.3	5	pF
f _T	transition frequency	V_{CE} = -12 V; f = 100 MHz; T_{amb} = 25 °C; I_{E} = -2 mA	-	190	-	MHz
TR2 (NPN)			,		,	
V _{CEsat}	collector-emitter saturation voltage	I _C = 50 mA; I _B = 5 mA; T _{amb} = 25 °C	-	-	250	mV
C _c	collector capacitance	V_{CB} = 12 V; I_{E} = 0 A; i_{e} = 0 A; f = 1 MHz; T_{amb} = 25 °C	-	-	3	pF
f _T	transition frequency	V _{CE} = 12 V; f = 100 MHz; T _{amb} = 25 °C; I _E = 2 mA	100	-	-	MHz

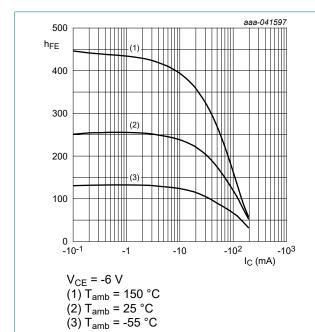


Fig. 1. PNP transistor: DC current gain as a function of collector current; typical values

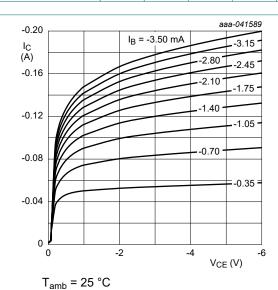
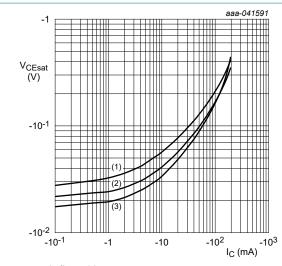


Fig. 2. PNP transistor: Collector current as a function of collector-emitter voltage; typical values

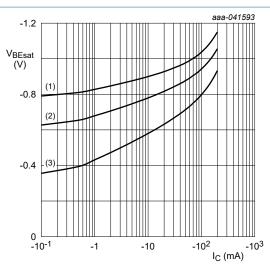
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 $I_C/I_B = 10$ (1) $T_{amb} = 150 \, ^{\circ}C$

(2) $T_{amb} = 25 \,^{\circ}C$ (3) $T_{amb} = -55 \,^{\circ}C$

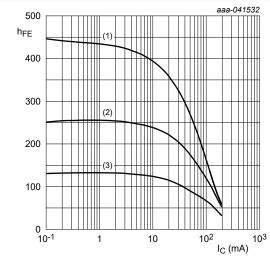
Fig. 3. **PNP** transistor: Collector-emitter saturation voltage as a function of collector current; typical values



 $I_{\rm C}/I_{\rm B} = 10$ (1) $T_{\rm amb} = -55 \,^{\circ}{\rm C}$

(2) T_{amb} = 25 °C (3) T_{amb} = 150 °C

Fig. 4. PNP transistor: Base-emitter saturation voltage as a function of collector current; typical values

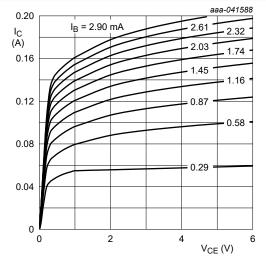


 $V_{CE} = 6 V$

 $(1) T_{amb} = 150 °C$

(2) $T_{amb} = 25 \,^{\circ}\text{C}$ (3) $T_{amb} = -55 \,^{\circ}\text{C}$

NPN transistor: DC current gain as a function of Fig. 5. collector current; typical values



T_{amb} = 25 °C

Fig. 6. NPN transistor: Collector current as a function of collector-emitter voltage; typical values

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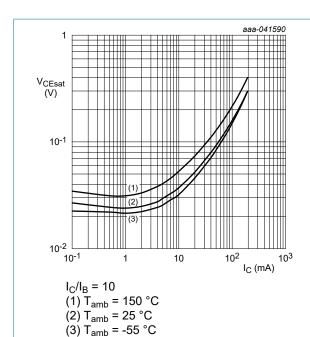


Fig. 7. NPN transistor: Collector-emitter saturation voltage as a function of collector current; typical values

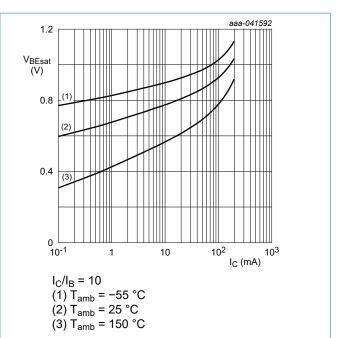


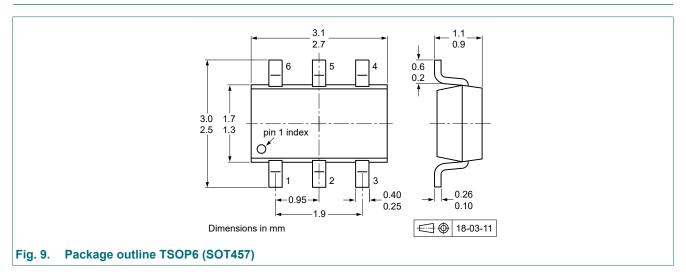
Fig. 8. NPN transistor: Base-emitter saturation voltage as a function of collector current; typical values

11. Test information

Quality information

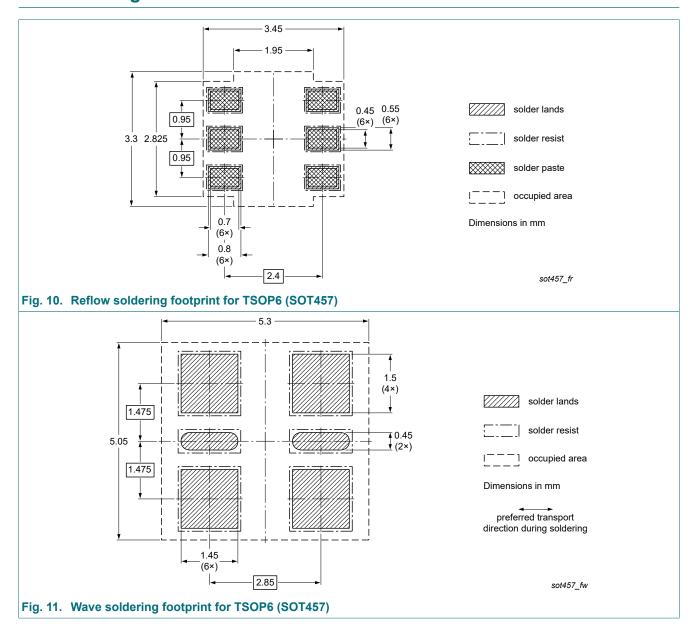
This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard *Q101 - Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

12. Package outline



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13. Soldering



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14. Revision history

Table 8. Revision history

Data sheet ID	Release date	Data sheet status	Change notice	Supersedes
PIMZ2-Q v.1	20250226	Product data sheet	-	-

15. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions".
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